

# **Isc N-Channel MOSFET Transistor**

## IPA60R380P6

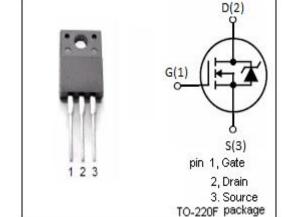
#### FEATURES

- With TO-220F package
- · Low input capacitance and gate charge
- · Low gate input resistance
- Reduced switching and conduction losses
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### APPLICATIONS

· Switching applications

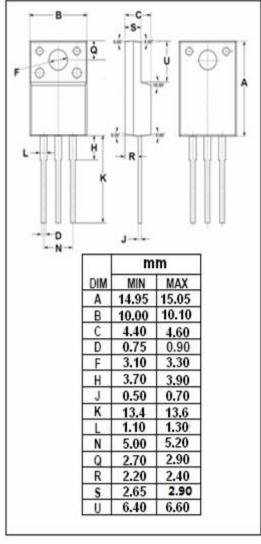


### ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	600	V	
V <sub>GSS</sub>	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current-Continuous @Tc=25℃ 10.6 (V <sub>GS</sub> at 10V) Tc=100℃ 6.7		А	
$I_{DM}$	Drain Current-Single Pulsed	29	А	
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	83	W	
Tj	Max. Operating Junction Temperature -55~150		$^{\circ}$ C	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$ C	

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	4	°C/W
Rth(ch-a)	a) Channel-to-ambient thermal resistance 80		°C/W



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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =1mA	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =0.32mA	3.5	4	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =3.8A;Tj=25°C V <sub>GS</sub> = 10V; I <sub>D</sub> =3.8A; Tj=150°C		0.342 0.889	0.38	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0V;Tj=25°C V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0V; Tj=150°C		10	1	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =4.8A, V <sub>GS</sub> = 0 V		0.9		V



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